onsemi

MARKING

DIAGRAMS

TinyLogic UHS Buffer with Three-State Output

NC7SZ125

Description

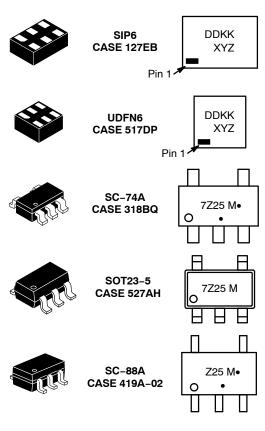
The NC7SZ125 is a single buffer with three-state output from **onsemi**'s Ultra-High Speed (UHS) of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive while maintaining low static power dissipation over a very broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V range. The inputs and output are high impedance above ground when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V independent of V_{CC} operating voltage. The output tolerates voltages above V_{CC} when in the 3–STATE condition.

Features

- Ultra-High Speed: $t_{PD} = 2.6$ ns (Typical) into 50 pF at 5 V V_{CC}
- High Output Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Matches Performance of LCX when Operated at 3.3 V V_{CC}
- Power Down High–Impedance Inputs / Outputs
- Over–Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Ultra-Small MicroPakTM Packages
- Space-Saving SOT23-5, SC-74A and SC-88A Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol

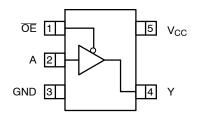


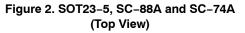
DD, 7Z25	5, Z25 = Specific Device Code
KK	= 2-Digit Lot Run Traceability Code
XY	= 2-Digit Date Code Format
Z	= Assembly Plant Code
М	= Date Code
•	= Pb-Free Package
	(Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

Pin Configurations





PIN DEFINITIONS

Pin # SOT23-5 / SC-88A / SC74A	Pin # MicroPak	Name	Description
1	1	ŌĒ	Input
2	2	А	Input
3	3	GND	Ground
4	4	Y	Output
5	6	V _{CC}	Supply Voltage
	5	NC	No Connect

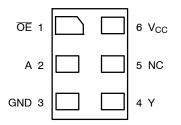


Figure 3. MicroPak (Top Through View)

FUNCTION TABLE

Inp	Output	
ŌE	А	Y
L	L	L
L	Н	Н
Н	Х	Z

H = HIGH Logic Level L = LOW Logic Level X = HIGH or LOW Logic Level Z = HIGH Impedance State

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Min	Мах	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{IN}	DC Input Voltage		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	6.5	V
I _{IK}	DC Input Diode Current	V _{IN} < 0 V	-	-50	mA
Ι _{ΟΚ}	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
I _{OUT}	DC Output Current	•	-	±50	mA
$I_{CC} \text{ or } I_{GND}$	DC V _{CC} or Ground Current		-	±50	mA
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature Under Bias		-	+150	°C
ΤL	Junction Lead Temperature (Solde	ering, 10 Seconds)	-	+260	°C
PD	Power Dissipation in Still Air	SC-74A / SOT23-5	-	390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	
		MicroPak2™–6	-	812	
ESD	Human Body Model, JEDEC: JESD22-A114		-	4000	V
	Charge Device Model, JEDEC: JE	SD22-C101	-	2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage Operating		1.65	5.50	V
	Supply Voltage Data Retention		1.50	5.50	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage	Active State	0	V _{CC}	V
		Three-State	0	5.5	
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Times	V_{CC} at 1.8 V, 2.5 V ± 0.2 V	0	20	ns/V
		V_{CC} at 3.3 V ± 0.3 V	0	10	
		V_{CC} at 5.0 V ± 0.5 V	0	5	
θ_{JA}	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	
		MicroPak2-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.
Unused inputs must be held HIGH or LOW. They may not float.

NC7SZ125

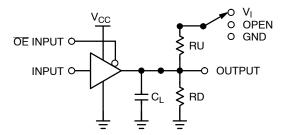
DC ELECTRICAL CHARACTERISTICS

				Т	λ = +25°	°C	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V_{IH}	HIGH Level Input Voltage	1.65 to 1.95		0.65 V _{CC}	-	-	0.65 V _{CC}	-	V
		2.30 to 5.50		0.70 V _{CC}	-	-	0.70 V _{CC}	-	1
VIL	LOW Level Input Voltage	1.65 to 1.95		-	-	0.35 V _{CC}	-	0.35 V _{CC}	V
		2.30 to 5.50		-	-	0.30 V _{CC}	-	0.30 V _{CC}	
V _{OH}	HIGH Level Output Voltage	1.65	$V_{IN} = V_{IH} \text{ or } V_{IL},$	1.55	1.65	-	1.55	-	V
		1.80	I _{OH} = -100 μA	1.70	1.80	-	1.70	-	
		2.30		2.20	2.30	-	2.20	-	
		3.00		2.90	3.00	-	2.90	-	
		4.50		4.40	4.50	-	4.40	-	
		1.65	I _{OH} = -4 mA	1.29	1.52	-	1.29	-	
		2.30	I _{OH} = -8 mA	1.90	2.15	-	1.90	-	
		3.00	I _{OH} = -16 mA	2.40	2.80	-	2.40	-	1
		3.00	I _{OH} = -24 mA	2.30	2.68	-	2.30	-	
		4.50	I _{OH} = -32 mA	3.80	4.20	-	3.80	-	
V _{OL}	LOW Level Output Voltage	1.65	$V_{IN} = V_{IH}$ or V_{IL} ,	-	0.00	0.10	_	0.00	V
		1.80	I _{OL} = 100 μA	-	0.00	0.10	_	0.10	
		2.30		-	0.00	0.10	_	0.10	1
		3.00		-	0.00	0.10	_	0.10	
		4.50		-	0.00	0.10	-	0.10	
		1.65	I _{OL} = 4 mA	-	0.80	0.24	-	0.24	
		2.30	I _{OL} = 8 mA	-	0.10	0.30	-	0.30	
		3.00	I _{OL} = 16 mA	-	0.15	0.40	-	0.40	
	3.00	I _{OL} = 24 mA	-	0.22	0.55	-	0.55		
		4.50	I _{OL} = 32 mA	-	0.22	0.55	-	0.55	
I _{IN}	Input Leakage Current	1.65 to 5.5	$0 \geq V_{IN} \geq 5.5 \ V$	-	-	±1	-	±10	μA
I _{OZ}	3-STATE Output Leakage	0 to 5.5	$\begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ 0 \geq V_O \geq 5.5 \ V \end{array}$	-	-	±1	-	±10	μΑ
I _{OFF}	Power Off Leakage Current	0	V_{IN} or V_{OUT} = 5.5 V	-	-	1	-	10	μA
I _{CC}	Quiescent Supply Current	1.65 to 5.50	V _{IN} = 5.5 V, GND	-	-	2	-	20	μA

AC ELECTRICAL CHARACTERISTICS

					T _A = +25°C)	T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay (Figure 4, 6)	1.65	$C_L = 15 \text{ pF},$	-	6.4	13.2	-	13.8	ns
		1.80	$R_D = 1 M\Omega$ S ₁ =OPEN	-	5.3	11.0	-	11.5	
		2.50 ± 0.20		-	3.4	7.5	-	8.0	
		$3.30\pm\!\!0.30$		-	2.5	5.2	-	5.5	
		5.00 ±0.50		-	2.1	4.5	-	4.8	
		$3.30\pm\!\!0.30$		-	3.2	5.7	-	6.0	
		5.00 ±0.50	· R _D = 500 Ω S ₁ = OPEN	-	2.6	5.0	-	5.3	
t _{PZL} , t _{PZH}	Output Enable Time	1.65	$C_L = 50 \text{ pF},$	-	8.4	15.0	-	15.6	ns
	(Figure 4, 6)	1.80	$\begin{array}{l} R_{D} = 500 \ \Omega \\ RU = 500 \ \Omega \\ S_1 = GND \text{ for } t_{PZH} \\ S_1 = V_{IN} \text{ for } t_{PZL} \end{array}$	-	7.0	12.5	-	13.0	
		2.50 ± 0.20		-	4.6	8.5	-	9.0	
		$3.30\pm\!\!0.30$	$V_{\rm IN} = 2 \cdot V_{\rm CC}$	-	3.5	6.2	-	6.5	
		$5.00\pm\!\!0.50$		-	2.8	5.5	-	5.8	
t_{PLZ}, t_{PHZ}	Output Disable Time	1.65	$C_{L} = 50 \text{ pF},$	-	6.5	13.2	-	14.5	
	(Figure 4, 6) $R_D = 500 \Omega$ RU = 500 Ω	-	5.4	11.0	-	12.0			
		2.50 ± 0.20	$S_1 = GND$ for t_{PHZ} $S_1 = V_{IN}$ for t_{PLZ}	-	3.5	8.0	-	8.5	
		$3.30\pm\!\!0.30$	$V_{IN} = 2 \cdot V_{CC}$	-	2.8	5.7	-	6.0	1
		$5.00\pm\!\!0.50$		-	2.1	4.7	-	5.0	
C _{IN}	Input Capacitance	0.00		-	4	-	-	-	pF
C _{OUT}	Output Capacitance	0.00		-	8	-	-	-	
C _{PD}	Power Dissipation Capacitance (Note 2) (Figure 5)	3.30		-	17	-	-	-	pF

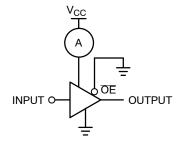
2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression:
I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).



NOTE:

3. C_L includes load and stray capacitance; Input PRR = 1.0 MHz; t_W = 500 ns

Figure 4. AC Test Circuit



NOTE:

4. Input = AC Waveform; $t_r = t_f = 1.8$ ns; PRR = 10 MHz; Duty Cycle = 50%.

Figure 5. I_{CCD} Test Circuit

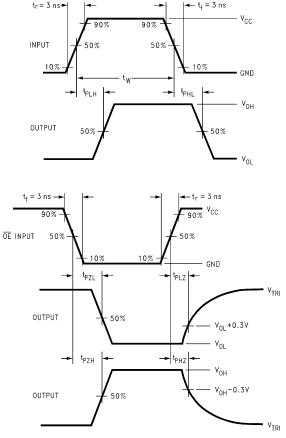


Figure 6. AC Waveforms

Part Number	Top Mark	Operating Temperature	Packages	Shipping [†]
NC7SZ125M5X	7Z25	−40 to +85°C	SC-74A	3000 / Tape & Reel
NC7SZ125M5X-L22090	7Z25	−40 to +85°C	SOT23-5	3000 / Tape & Reel
NC7SZ125P5X	Z25	−40 to +85°C	SC-88A	3000 / Tape & Reel
NC7SZ125P5X-F22057	Z25	−40 to +85°C	SC-88A	3000 / Tape & Reel
NC7SZ125L6X	DD	−40 to +85°C	MicroPak	5000 / Tape & Reel
NC7SZ125L6X-L22175	DD	−40 to +85°C	MicroPak	5000 / Tape & Reel
NC7SZ125FHX	DD	−40 to +85°C	MicroPak2	5000 / Tape & Reel
NC7SZ125FHX-L22175	DD	−40 to +85°C	MicroPak2	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MicroPak and MicroPak2 are trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries.

ORDERING INFORMATION

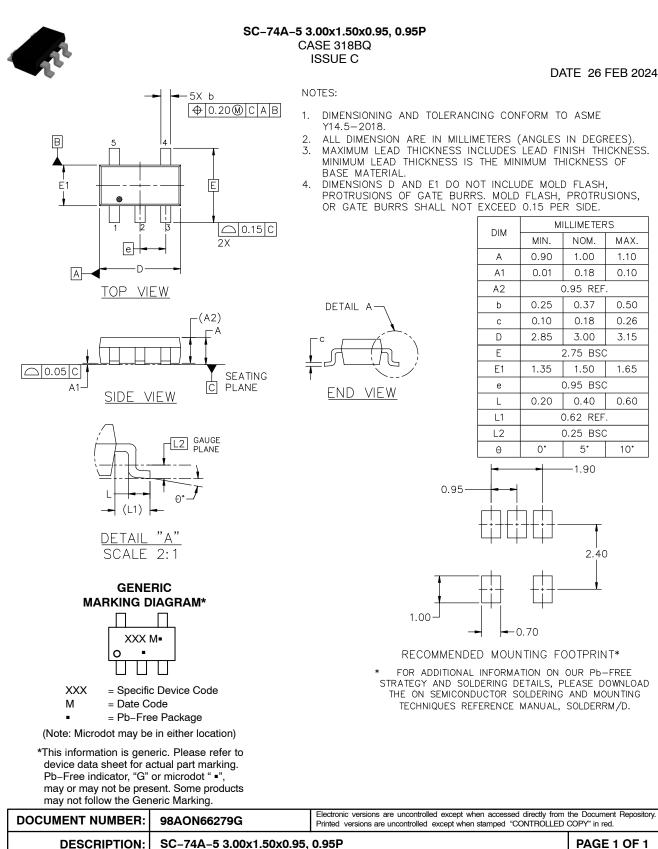


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DATE 31 AUG 2016



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SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

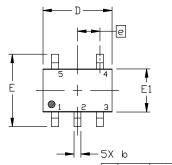
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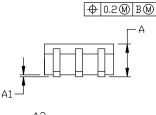
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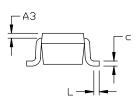
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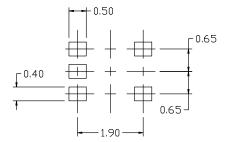
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DATE 11 APR 2023









RECOMMENDED MOUNTING FOOTPRINT

 For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

лтм	MI	MILLIMETERS			
DIM	MIN.	NDM.	MAX.		
Α	0.80	0.95	1.10		
A1			0.10		
A3		0.20 REF			
b	0.10	0.20	0.30		
C	0.10		0.25		
D	1.80	2.00	2.20		
E	2.00	2.10	2.20		
E1	1.15	1.25	1.35		
e	0.65 BSC				
L	0.10	0.15	0.30		

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSDLETE, NEW STANDARD 419A-02

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

(Note: Microdot may be in either location)

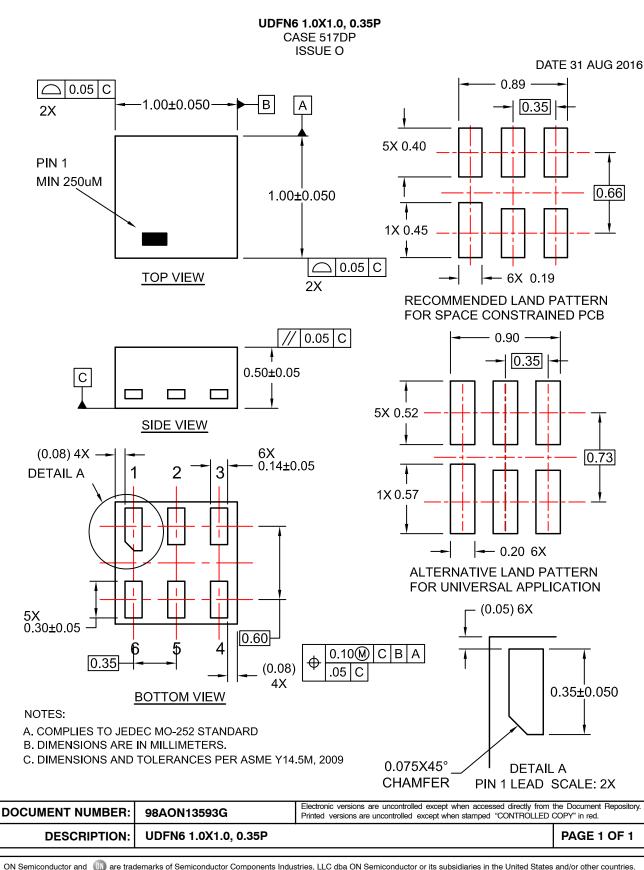
DOCUMENT NUMBER: 98ASB42984B Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. DESCRIPTION: SC-88A (SC-70-5/SOT-353) PAGE 1 OF 1	PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	style callout. If style t out in the datasheet r datasheet pinout or p	refer to the device
DESCRIPTION: SC-88A (SC-70-5/SOT-353) PAGE 1 OF 1	DOCUMENT NUMBER:	98ASB42984B				
	DESCRIPTION:	SC-88A (SC-70-	5/SOT–353)			PAGE 1 OF 1

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XXX = Specific Device Code

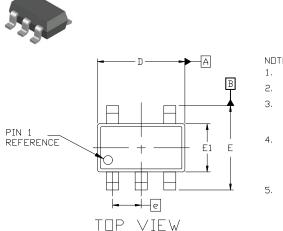
M = Date Code = Pb-Free Package





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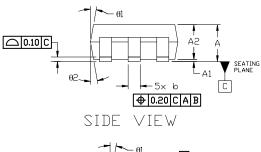


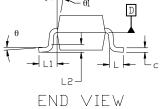
SOT-23, 5 Lead CASE 527AH **ISSUE A**

DATE 09 JUN 2021

NDTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.





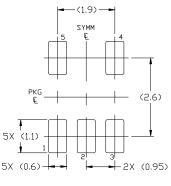
GENERIC **MARKING DIAGRAM***



XXX = Specific Device Code = Date Code М

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

	MILLIMETERS					
DIM	MIN.	NDM.	MAX.			
Α	0.90	_	1.45			
A1	0.00	—	0.15			
A2	0.90	1.15	1.30			
b	0.30	_	0.50			
С	0.08	_	0.22			
D	2	2.90 BSC				
E	2	.80 BSC				
E1	1	1.60 BSC				
e	0	0.95 BSC				
L	0.30	0.45	0.60			
L1	0.60 REF					
L2	0.25 REF					
θ	0*	4°	8 °			
01	0*	10°	15°			
02	0°	10°	15°			



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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